

Substitute for form 1449A/B/PTO				Complete if Known				
		•	•	Application Number	10/672,961 (Conf. No. 9439)			
IN	NFORMATION	I DI	SCLOSURE	Filing Date	September 26, 2003			
S	TATEMENT E	3Y /	APPLICANT	First Named Inventor	Glenn J. Leedy			
				Art Unit	2822			
	(Use as many sh	eets as	necessary)	Examiner Name	Monica Lewis			
Sheet 1 of 2				Attorney Docket Number	ELM-2 Cont. 4			

LIS DATENT DOCUMENTS

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Examiner Initials*	Cite No.	Document Number Number-Kind Code ² (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
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Examiner Signature	Date Considered	100
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PTO/SB/08a/b (08-03)
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Sut	ostitute for form 1449A/B	/PTO		Complete If Known				
00.	33,113,10 101 101111 14 107 12			Application Number	10/672,961 (Conf. No. 9439)			
11	NFORMATIC	ON DIS	SCLOSURE	Filing Date	September 26, 2003			
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Sheet	2	2 of 2		Attorney Docket Number	ELM-2 Cont. 4			

NON PATENT LITERATURE DOCUMENTS								
Examiner Initials	Cite No.1 Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the iten magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publishe and/or country where published.							
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*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. *Applicant's unique citation designation number (optional). *See Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. *Enter Office that Issued the document, by the two-letter code (WIPO Standard ST.3). *For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. *Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. *Applicant is to place a check mark here if English language Translation is attached.

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